# NSN 5961-01-062-5743

Transistor - Page 1 of 1



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## Inclosure Material:

Ceramic and metal

## **Overall Length:**

0.640 inches

Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

## **Mounting Method:**

Threaded stud

## Thread Size:

0.164 inches

## Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

55.0 breakdown voltage, collector-to-base, emitter open and 33.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown

voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

250.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Ceramic case contains beryllium oxide - handle and dispose iaw hazmat procedures; junction pattern arrangement: npn

#### **Precious Material And Location:**

Chip metallization and internal @wires gold

#### **Precious Material:**

Gold

## Test Data Document:

13499-352-1059 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Thread Series Designator:**

Unc

## Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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